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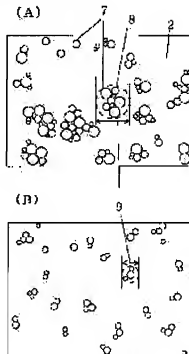
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(54) LIGHT-EMITTING DIODE AND MANUFACTURING METHOD THEREFOR

(57)Abstract:

PROBLEM TO BE SOLVED: To provide a color-conversion-type light-emitting diode that has a superior yield, a converged color tone, and high lighting intensity.
SOLUTION: In this light-emitting diode having a light-emitting device where a light-emitting layer is composed by a nitride-family compound semiconductor, a resin member that contains a phosphor for absorbing at least one part of light with wavelength being emitted by the light-emitting device and for emitting the light with different wavelength, wet dispersion treatment is performed to liquid resin containing the phosphor in advance so that the phosphor composes an aggregate, having an average particle size of 3 to 50 μm .



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